



OPA121

Low Cost Precision *Difet*® OPERATIONAL AMPLIFIER

FEATURES

LOW NOISE: 6nV/√Hz typ at 10kHz
 LOW BIAS CURRENT: 5pA max

LOW OFFSET: 2mV max
 LOW DRIFT: 3µV/°C typ

● HIGH OPEN-LOOP GAIN: 110dB min

 HIGH COMMON-MODE REJECTION: 86dB min

DESCRIPTION

The OPA121 is a precision monolithic dielectrically-isolated FET (*Difet*®) operational amplifier. Outstanding performance characteristics are now available for low-cost applications.

Noise, bias current, voltage offset, drift, open-loop gain, common-mode rejection, and power supply rejection are superior to BIFET® amplifiers.

Very low bias current is obtained by dielectric isolation with on-chip guarding.

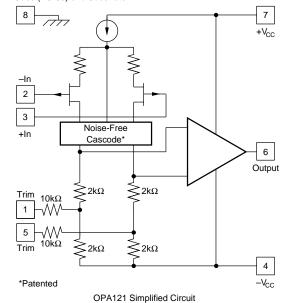
Laser-trimming of thin-film resistors gives very low offset and drift. Extremely low noise is achieved with new circuit design techniques (patented). A new cascode design allows high precision input specifications and reduced susceptibility to flicker noise.

Standard 741 pin configuration allows upgrading of existing designs to higher performance levels.

APPLICATIONS

- **OPTOELECTRONICS**
- DATA ACQUISITION
- TEST EQUIPMENT
- MEDICAL EQUIPMENT
- **RADIATION HARD EQUIPMENT**

Case (TO-99) and Substrate



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BIFET®, National Semiconductor Corp.

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SPECIFICATIONS

ELECTRICAL

At V_{CC} = ± 15 VDC and T_A = +25°C unless otherwise noted. Pin 8 connected to ground.

			OPA121KM			OPA121KP, KU		
PARAMETER	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
INPUT								
Voltage, f_O = 10Hz f_O = 100Hz f_O = 100Hz f_O = 10kHz f_B = 10Hz to 10kHz f_B = 0.1Hz to 10 Hz Current, f_B = 0.1Hz to 10Hz	(1) (1) (1) (1) (1) (1) (1)		40 15 8 6 0.7 1.6			50 18 10 7 0.8 2 21		nV/√Hz nV/√Hz nV/√Hz nV/√Hz μVrms μVp-p fA, p-p
f _O = 0.1Hz thru 20kHz OFFSET VOLTAGE ⁽²⁾	(1)		0.8			1.1		fA/√Hz
Input Offset Voltage Average Drift Supply Rejection	$V_{CM} = 0 VDC$ $T_A = T_{MIN} \text{ to } T_{MAX}$	86	±0.5 ±3 104 ±6	±2 ±10 ±50	86	±0.5 ±3 104 ±6	±3 ±10 ±50	mV μV/°C dB μV/V
BIAS CURRENT ⁽²⁾ Input Bias Current	V _{CM} = 0VDC Device Operating		±1	±5		±1	±10	pA
OFFSET CURRENT ⁽²⁾ Input Offset Current	V _{CM} = 0VDC Device Operating		±0.7	±4		±0.7	±8	pA
IMPEDANCE Differential Common-Mode			10 ¹³ 1 10 ¹⁴ 3			10 ¹³ 1 10 ¹⁴ 3		Ω pF Ω pF
VOLTAGE RANGE Common-Mode Input Range Common-Mode Rejection	V _{IN} = ±10VDC	±10 86	±11 104		±10 82	±11 100		V dB
OPEN-LOOP GAIN, DC Open-Loop Voltage Gain	$R_L \ge 2k\Omega$	110	120		106	114		dB
FREQUENCY RESPONSE Unity Gain, Small Signal Full Power Response Slew Rate Settling Time, 0.1% 0.01% Overload Recovery, 50% Overdrive(3)	$20 \text{Vp-p, } R_L = 2k\Omega$ $\text{V}_O = \pm 10 \text{V, } R_L = 2k\Omega$ $\text{Gain = -1, } R_L = 2k\Omega$ 10V Step Gain = -1		2 32 2 6 10			2 32 2 6 10		MHz kHz V/μs μs μs
RATED OUTPUT Voltage Output Current Output Output Resistance Load Capacitance Stability Short Circuit Current	$R_L = 2k\Omega$ $V_O = \pm 10 \text{VDC}$ $DC, Open Loop$ $Gain = +1$	±11 ±5.5	±12 ±10 100 1000 40		±11 ±5.5	±12 ±10 100 1000 40		V mA Ω pF mA
POWER SUPPLY Rated Voltage			±15			±15		VDC
Voltage Range, Derated Performance Current, Quiescent	I _O = 0mADC	±5	2.5	±18 4	±5	2.5	±18 4.5	VDC VDC mA
TEMPERATURE RANGE Specification Operating Storage θ Junction-Ambient	Ambient Temperature Ambient Temperature Ambient Temperature	0 -40 -65	200	+70 +85 +150	0 -25 -55	150 ⁽⁴⁾	+70 +85 +125	°C °C °C/W

NOTES: (1) Sample tested. (2) Offset voltage, offset current, and bias current are specified with the units fully warmed up. (3) Overload recovery is defined as the time required for the output to return from saturation to linear operation following the removal of a 50% input overdrive. (4) 100°C/W for KU grade.

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ELECTRICAL (FULL TEMPERATURE RANGE SPECIFICATIONS)

At $V_{CC} = \pm 15 \text{VDC}$ and $T_A = T_{MIN}$ to T_{MAX} unless otherwise noted.

			OPA121KM		C	PA121KP, KU		
PARAMETER	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
TEMPERATURE RANGE Specification Range	Ambient Temperature	0		+70	0		+70	°C
INPUT OFFSET VOLTAGE(1) Input Offset Voltage Average Drift Supply Rejection	OFFSET VOLTAGE(1) Input Offset Voltage V _{CM} = 0VDC Average Drift V		±1 ±3 94 ±20	±3 ±10 ±80	82	±1 ±3 94 ±20	±5 ±10 ±80	mV μV/°C dB μV/V
BIAS CURRENT ⁽¹⁾ Input Bias Current	V _{CM} = 0VDC Device Operating		±23	±115		±23	±250	pA
OFFSET CURRENT ⁽¹⁾ Input Offset Current	V _{CM} = 0VDC Device Operating		±16	±100		±16	±200	pA
VOLTAGE RANGE Common-Mode Input Range Common-Mode Rejection	V _{IN} = ±10VDC	±10 82	±11 98		±10 80	±11 96		V dB
OPEN-LOOP GAIN, DC Open-Loop Voltage Gain	$R_L \ge 2k\Omega$	106	116		100	110		dB
RATED OUTPUT Voltage Output Current Output Short Circuit Current	$R_{L} = 2k\Omega$ $V_{O} = \pm 10VDC$ $V_{O} = 0VDC$	±10.5 ±5.25 10	±11 ±10 40		±10.5 ±5.25 10	±11 ±10 40		V mA mA
POWER SUPPLY Current, Quiescent	I _O = 0mADC		2.5	4.5		2.5	5	mA

NOTE: (1) Offset voltage, offset current, and bias current are measured with the units fully warmed up.

ABSOLUTE MAXIMUM RATINGS

Supply Internal Power Dissipation ⁽¹⁾	
· '	
Differential Input Voltage	±36VDC
Input Voltage Range	±18VDC
Storage Temperature Range	
M package	-65°C to +150°C
P, U packages	-55°C to +125°C
Operating Temperature Range	
M package	40°C to +85°C
P, U packages	–25°C to +85°C
Lead Temperature	
M, P packages (soldering, 10s)	+300°C
U package (soldering, 3s)	
Output Short-Circuit Duration ⁽²⁾	Continuous
Junction Temperature	+175°C

NOTES: (1) Packages must be derated based on $\theta_{JA} = 150^{\circ}\text{C/W}$ (P package); $\theta_{JA} = 200^{\circ}\text{C/W}$ (M package); $\theta_{JA} = 100^{\circ}\text{C/W}$ (U package). (2) Short circuit may be to power supply common only. Rating applies to +25°C ambient. Observe dissipation limit and T_{J} .

PACKAGE INFORMATION

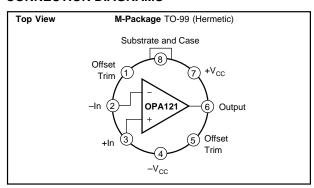
MODEL	PACKAGE	PACKAGE DRAWING NUMBER ⁽¹⁾
OPA121KM	TO-99	001
OPA121KP	8-Pin Plastic DIP	006
OPA121KU	8-Pin SOIC	182

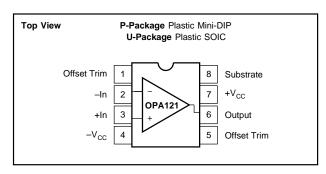
NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix D of Burr-Brown IC Data Book.

ORDERING INFORMATION

MODEL	PACKAGE	TEMPERATURE RANGE		
OPA121KM	TO-99	0°C to +70°C		
OPA121KP	8-Pin Plastic DIP	0°C to +70°C		
OPA121KU	8-Pin SOIC	0°C to +70°C		

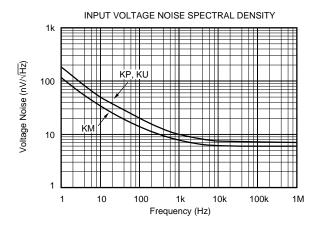
CONNECTION DIAGRAMS

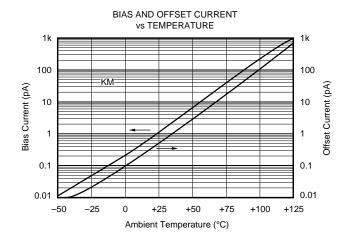


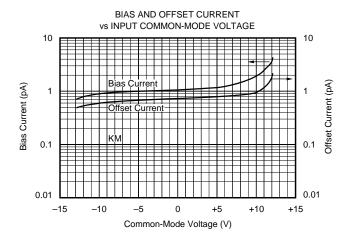


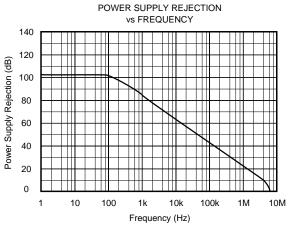
TYPICAL PERFORMANCE CURVES

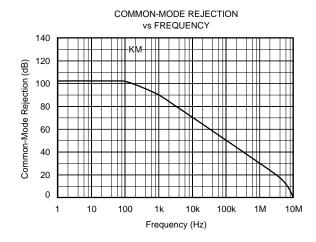
 T_A = +25°C, V_{CC} = ±15VDC unless otherwise noted.

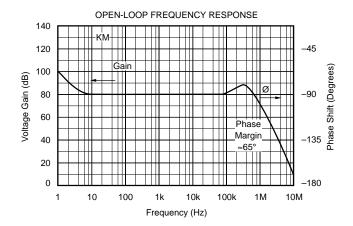






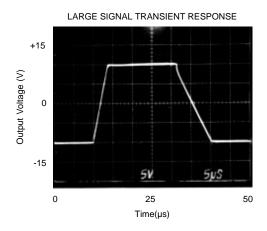


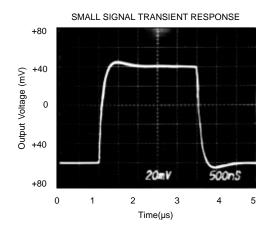


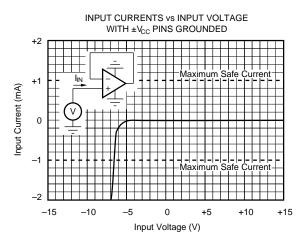


TYPICAL PERFORMANCE CURVES (CONT)

 $T_A = +25$ °C, $V_{CC} = \pm 15$ VDC unless otherwise noted.







APPLICATIONS INFORMATION

OFFSET VOLTAGE ADJUSTMENT

The OPA121 offset voltage is laser-trimmed and will require no further trim for most applications. As with most amplifiers, externally trimming the remaining offset can change drift performance by about $0.3\mu V/^{\circ}C$ for each $100\mu V$ of adjusted offset. Note that the trim (Figure 1) is similar to operational amplifiers such as 741 and AD547. The OPA121 can replace most BIFET amplifiers by leaving the external null circuit unconnected.

INPUT PROTECTION

Conventional monolithic FET operational amplifiers require external current-limiting resistors to protect their inputs against destructive currents that can flow when input FET gate-to-substrate isolation diodes are forward-biased. Most BIFET amplifiers can be destroyed by the loss of $-V_{CC}$.

Unlike BIFET amplifiers, the **Difet** OPA121 requires input current limiting resistors only if its input voltage is greater

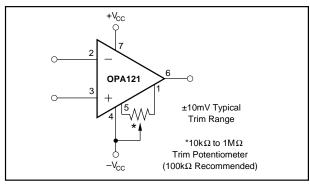


FIGURE 1. Offset Voltage Trim.

than 6V more negative than $-V_{CC}$. A $10k\Omega$ series resistor will limit input current to a safe level with up to $\pm 15V$ input levels even if both supply voltages are lost.

Static damage can cause subtle changes in amplifier input characteristics without necessarily destroying the device. In precision operational amplifiers (both bipolar and FET types),

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this may cause a noticeable degradation of offset voltage and drift.

Static protection is recommended when handling any precision IC operational amplifier.

GUARDING AND SHIELDING

As in any situation where high impedances are involved, careful shielding is required to reduce "hum" pickup in input leads. If large feedback resistors are used, they should also be shielded along with the external input circuitry.

Leakage currents across printed circuit boards can easily exceed the bias current of the OPA121. To avoid leakage problems, it is recommended that the signal input lead of the OPA121 be wired to a TeflonTM standoff. If the OPA121 is to be soldered directly into a printed circuit board, utmost care must be used in planning the board layout. A "guard" pattern should completely surround the high-impedance input leads and should be connected to a low-impedance point which is at the signal input potential.

The amplifier case should be connected to any input shield or guard via pin 8. This insures that the amplifier itself is fully surrounded by guard potential, minimizing both leakage and noise pickup (see Figure #2).

If guarding is not required, pin 8 (case) should be connected to ground.

BIAS CURRENT CHANGE VERSUS COMMON-MODE VOLTAGE

The input bias currents of most popular BIFET operational amplifiers are affected by common-mode voltage (Figure 3). Higher input FET gate-to-drain voltage causes leakage and ionization (bias) currents to increase. Due to its cascode input stage, the extremely-low bias current of the OPA121 is not compromised by common-mode voltage.

TeflonTM E.I. du Pont de Nemours & Co.

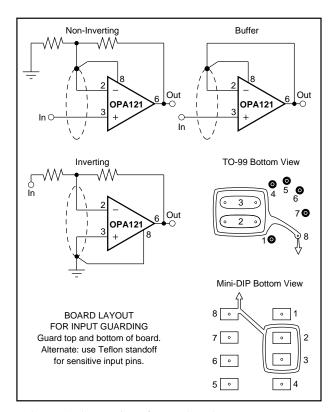


FIGURE 2. Connection of Input Guard.

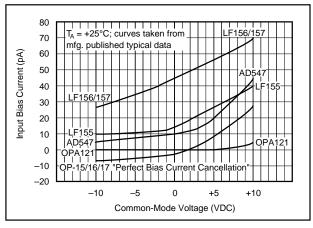


FIGURE 3. Input Bias Current vs Common-Mode Voltage.





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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
OPA121KM	OBSOLETE	TO-99	LMC	8		TBD	Call TI	Call TI
OPA121KM3	OBSOLETE	TO-99	LMC	8		TBD	Call TI	Call TI
OPA121KP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
OPA121KP4	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
OPA121KU	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
OPA121KU/2K5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
OPA121KU/2K5G4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
OPA121KUE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

	Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OP	A121KU/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

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*All dimensions are nominal

ĺ	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
	OPA121KU/2K5	SOIC	D	8	2500	346.0	346.0	29.0	

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